



栅极驱动光耦

Gate Drive Optocoupler

**QX155**

宁波群芯微电子股份有限公司

NINGBO QUNXIN MICROELECTRONICS CO., LTD.

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### 概述 Description

QX155 内部有一个 GaAlAs 红外发光二极管和集成的高增益、高速光电探测器。QX155 采用 SOP5 封装。光电探测器内部有一个法拉第屏蔽，保证  $\pm 20\text{kV}/\mu\text{s}$  的共模瞬态抗扰度。QX155 适用于 IGBTs 或功率 MOSFETs 的栅极驱动电路。

The QX155 consists of a GaAlAs infrared light-emitting diodes and integrated high gain, high-speed photodetector. The QX155 is housed in the SOP5 package. There is a Faraday shield inside the photodetector, which can guarantee the common mode transient immunity of  $\pm 20\text{kV}/\mu\text{s}$ . QX155 is suitable for direct gate driving circuit for IGBTs or power MOSFETs.

### 特性 Features

- 工作温度范围:  $-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ ;  
Operating temperature range:  $-40^{\circ}\text{C} \sim +105^{\circ}\text{C}$ ;
- 延迟时间最大为 200ns  
200ns maximum propagation delay
- 共模瞬态抗扰度:  $\pm 20\text{kV}/\mu\text{s}$ ;  
Common mode transient immunity:  $\pm 20\text{kV}/\mu\text{s}$  (min);
- 传播延迟倾斜:  $\pm 85\text{ns}$ ;  
Propagation delay skew:  $\pm 85\text{ns}$  (max)
- 隔离电压:  $3750 V_{\text{rms}}$  (最小值)  
Isolation voltage:  $3750 V_{\text{rms}}$  (min)
- 符合加强绝缘标准  
Meet reinforced insulation standards.

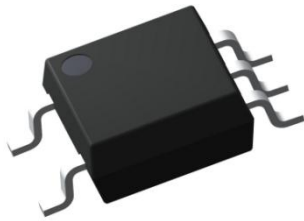
### 应用 Applications

- 等离子显示面板(PDPs)  
Plasma Display Panels (PDPs)
- 晶体管逆变器  
Transistor Inverters
- MOSFET 栅极驱动器  
MOSFET Gate Drivers
- IGBT 栅极驱动器  
IGBT Gate Drivers

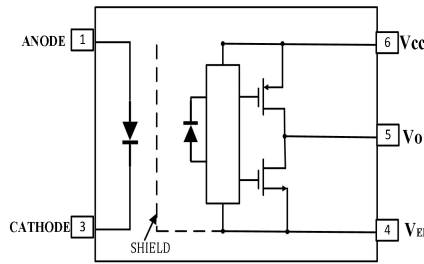
### 真值表 Truth table

LED	$V_{\text{CC}}-V_{\text{SS}}$ " POSITIVE GOING" (TURN-ON)	$V_{\text{CC}}-V_{\text{SS}}$ "NEGATIVE GOING" (TURN-OFF)	VO
OFF	0~30V	0~30V	LOW
ON	0~6.9V	0~5.9V	LOW
ON	6.9~8.7V	5.9~7.5V	TRANSITION
ON	8.7~30V	7.5~30V	HIGH

**封装和原理图 Package and Schematic Diagram**



SOP5



Pin Configuration

- 1. Anode
- 3. Cathode
- 4. V<sub>EE</sub>
- 5. V<sub>O</sub>
- 6. V<sub>CC</sub>

注：在引脚 4 和 6 之间必须连接一个 0.1uF 的旁路电容器。

Note: A 0.1uF bypass capacitor must be connected between pins 4 and 6.

**产品型号命名规则 Order Code**

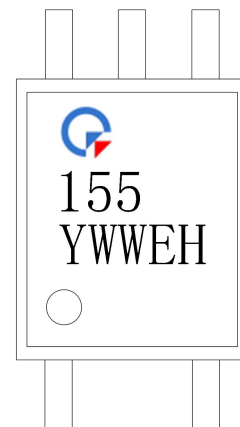
**QX 155 - UN Y - W V**

- ①
- ②
- ③
- ④
- ⑤
- ⑥

- ① 公司代码 Company Code (QX: 群芯 Qunxin)
- ② 产品系列 Product Series (155)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (S: SOP)
- ⑥ 产品版本 Product Versions: E

**印字信息 Marking Information**

- 印字中“”为群芯品牌 LOGO  
“”denotes LOGO
- 印字中“Y”代表年份: A(2018), B(2019), C(2020).....  
“Y”denotes YEAR: A(2018), B(2019), C(2020).....
- 印字中“WW”代表周号  
“WW”denotes Week’s number
- 印字中的“E”代表经济型产品  
“E”denotes the economical product.
- 印字中的“H”代表无卤  
“H”denotes Halogen-free



### 绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Note
爬电距离 Creepage Distance	L	≥5	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body.
电气间隙 Clearance Distance	L	≥5	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air.
绝缘距离 Insulation Thickness	DTI	≥0.3	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector.
峰值隔离电压 Peak Isolation Voltage	$V_{IORM}$	600	$V_{peak}$	DIN/EN/IEC EN60747-5-5.
瞬态隔离电压 Transient Isolation Voltage	$V_{IOTM}$	5000	$V_{peak}$	DIN/EN/IEC EN60747-5-5.
隔离电压 Isolation Voltage	$V_{ISO}$	3750	$V_{rms}$	$T_A = 25^{\circ}C$ , RH < 50% for 1 min.

### 极限参数 Absolute Maximum Ratings ( $T_A=25^{\circ}C$ )

参数 Parameter		符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
输入 Input	平均输入电流 Average Current Input	$I_{F(AVG)}$	-	20	mA
	峰值瞬态输入电流 (<1 us pulse, 300pps) Peak Transient Input Current (<1 us Pulse, 300pps)	$I_{F(TRAN)}$	-	1	A
	反向电压 Reverse Voltage	$V_R$	5	-	V
输出 Output	高峰值输出电流 High Peak Output Current	$I_{OH(PEAK)}$	-	-1	A
	低峰值输出电流 Low Peak Output Current	$I_{OL(PEAK)}$	-	1	A
	电源电压 Supply Voltage	$V_{CC}$	-	35	V
	峰值输出电压 Peak Output Voltage	$V_O$	-	35	V
隔离电压 Isolation Voltage		$V_{ISO}$	3750	-	$V_{rms}$
工作温度 Operating Temperature		$T_{opr}$	-40	+105	$^{\circ}C$
储存温度 Storage Temperature		$T_{STG}$	-55	+125	$^{\circ}C$
焊接温度 Soldering Temperature		$T_{sol}$	-	260	$^{\circ}C$

### 推荐操作条件 Recommended Operating Conditions

参数 Parameter	符号 Symbol	最小值 Min	最大值 Max.	单位 Unit
电源电压 Power Supply Voltage	$V_{CC}$	10	30	V
开启电流 Input Current (ON)	$I_{FLH}$	10	15	mA
关断电压 Input Voltage (OFF)	$V_{FHL}$	0	0.8	V
高电平峰值输出电流 Peak high-level output current	$I_{OH}$	-	-0.2	A
低电平峰值输出电流 Peak low-level output current	$I_{OL}$	-	0.2	A
工作温度 Operating temperature	$T_{opr}$	-40	+105	°C
工作频率 Operating frequency	F	-	250	kHz

### 产品特性参数 Electro-optical Characteristics ( $T_A=25^\circ\text{C}$ )

除非另有规定，适用于所有的推荐条件，典型值在  $V_{CC}=30\text{V}$ ,  $V_{SS}=\text{Ground}$ ,  $T_A=25^\circ\text{C}$  下测量

Unless otherwise specified, as appropriate for all recommended conditions, typical values are measured at  $V_{CC}=30\text{V}$ ,  $V_{SS}=\text{Ground}$ ,  $T_A=25^\circ\text{C}$ .

参数 Parameter	符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit	
发射端 Input	正向电压 Forward Voltage	$V_F$	$I_f=10\text{mA}$	1.2	1.4	1.8	V
	反向电压 Reverse Voltage	$B_{VR}$	$I_R=10\mu\text{A}$	5	-	-	V
	阈值电流从低到高 Threshold Input Current Low to High	$I_{FLH}$	$I_o=0\text{mA}$ $V_o > 5\text{V}$	-	0.6	7.5	mA
	阈值电压从高到低 Threshold Input Voltage High to Low	$V_{FHL}$	$I_o=0\text{mA}$ $V_o < 5\text{V}$	0.8	-	-	V
	输入正向电压的温度系数 Temperature Coefficient Of Input Forward Voltage	$\Delta V_F/\Delta T_A$	$I_f = 10\text{mA}$	-	-1.8	-	mV/°C
	输入电容 Input Capacitance	$C_{IN}$	$V=0$ , $F=1\text{kHz}$	-	85	-	pF
接收端 Output	高电平输出电流 High Level Output Current	$I_{OH}$	$V_O=V_{CC}-4\text{V}$	-	-0.5	-0.2	A
		$I_{OH}$	$V_O=V_{CC}-10\text{V}$	-	-	-0.4	
	低电平输出电流 Low Level Output Current	$I_{OL}$	$V_O=V_{SS}+2\text{V}$	0.2	0.5	-	
		$I_{OL}$	$V_O=V_{SS}+10\text{V}$	0.4	-	-	

参数 Parameter	符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit		
高电平输出电压 High Level Output Voltage	$V_{OH}$	$I_F = 10mA$ , $I_O = -100mA$	$V_{CC} - 0.6V$	$V_{CC} - 0.35V$	-	V		
低电平输出电压 Low Level Output Voltage	$V_{OL}$	$I_F = 0mA$ , $I_O = 100mA$	-	$V_{SS} + 0.25V$	$V_{SS} + 0.4V$	V		
高电平电源电流 High Level Power Supply Current	$I_{CCH}$	$I_F = 10mA$ , $V_{CC} = 10 \text{ to } 30V$	-	1.6	3	mA		
低电平电源电流 Low Level Power Supply Current	$I_{CCL}$	$I_F = 0mA$ , $V_{CC} = 10 \text{ to } 30V$	-	1.5	3			
传输特性 Transfer Characteristics	低电压锁定阈值 UVLO Threshold	$V_{UVLO+}$ $V_O > 5V$	6.9	7.8	8.7	V		
		$V_{UVLO-}$ $V_O < 5V$	5.9	6.7	7.5	V		
	低电压锁定阈值迟滞 UVLO Hysteresis	$U_{VLOHYS}$	-	1.1	-	V		
	低电平传输延迟 Propagation Delay Time to Low Output Level	$T_{PHL}$	$V_{CC} = 30V$ $I_F = 8mA$ $R_g = 47\Omega$ $C_g = 3nF$ $f = 10 \text{ kHz}$ Duty Cycle = 50%	50	170	250	ns	
	高电平传输延迟 Propagation Delay Time to High Output Level	$T_{PLH}$		50	120	250	ns	
	传输延迟差 Propagation Delay Difference Between Any Two Parts	PDD		-85	-	85	ns	
	上升时间(10%~90%) Rise Time (10% To 90%)	$T_R$		-	61	-	ns	
	下降时间(90%~10%) Fall Time (90%~10%)	$T_F$		-	60	-	ns	
	输出高电平共模抑制 Output High Level Common Mode Transient Immunity	$ CM_H $		$T_A = 25^\circ C$ $V_{CM} = 1500V$	20	-	-	kV/ $\mu s$
	输出低电平共模抑制 Output Low Level Common Mode Transient Immunity	$ CM_L $			20	-	-	kV/ $\mu s$
	隔离电阻 Isolation Resistance	$R_{ISO}$		$V_{I-O} \leq 500V$	$10^{12}$	-	-	$\Omega$
	隔离电容 Isolation Capacitance	$C_{ISO}$		$V_{I-O} = 0V$ $f = 1.0MHz$	-	0.9	-	pF

**典型光电特性曲线 Typical Electro-Optical Characteristics Curves**

Fig.1 High Level Output Voltage vs. Ambient Temperature

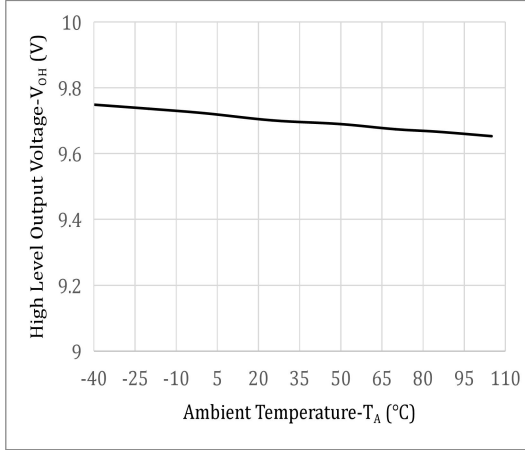


Fig.2 High Level Output Current vs. Ambient Temperature

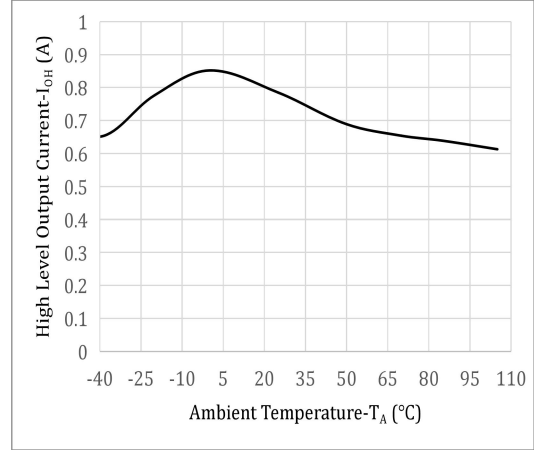


Fig.3 High Level Output Voltage vs. High Level Output Current

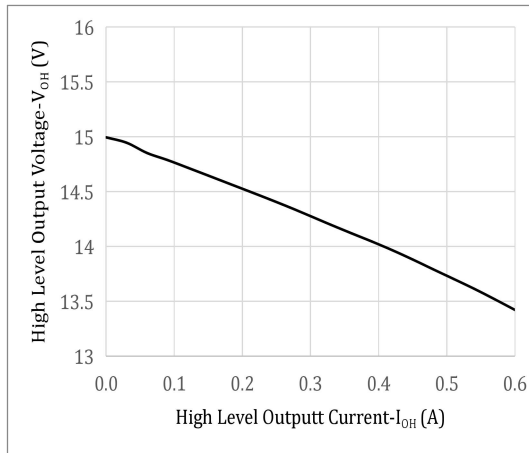


Fig.4 Low Level Output Voltage vs. Ambient Temperature

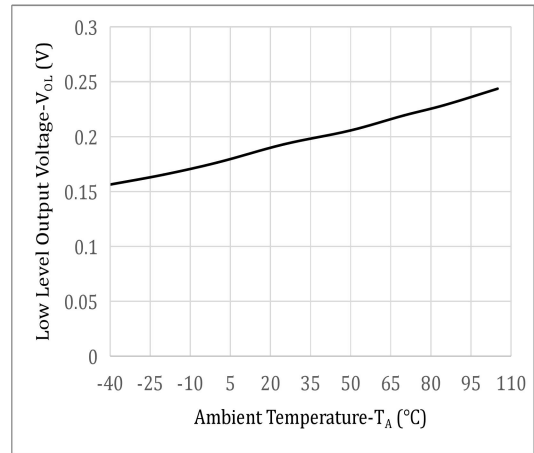


Fig.5 Low Level Output Current vs. Ambient Temperature

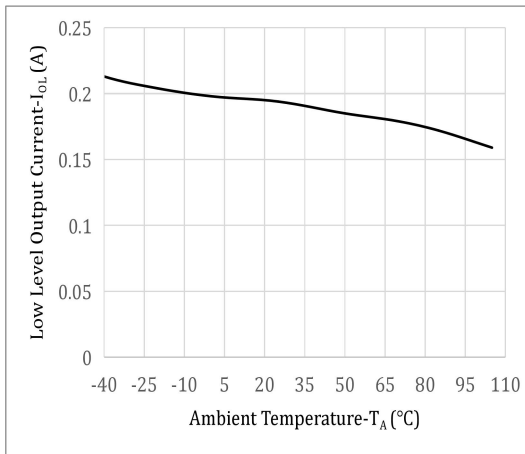


Fig.6 Low Level Output Voltage vs. Low Level Output Current

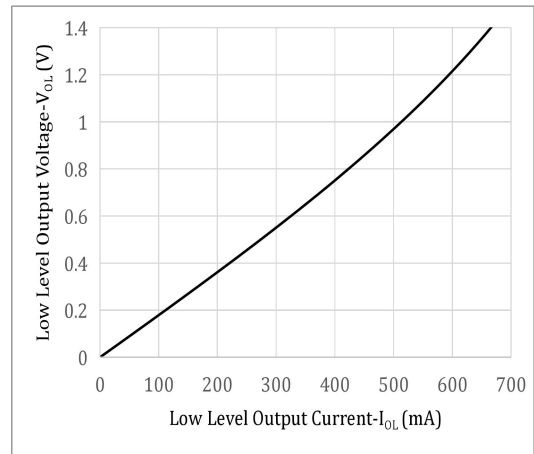


Fig.7 Supply Current vs. Ambient Temperature

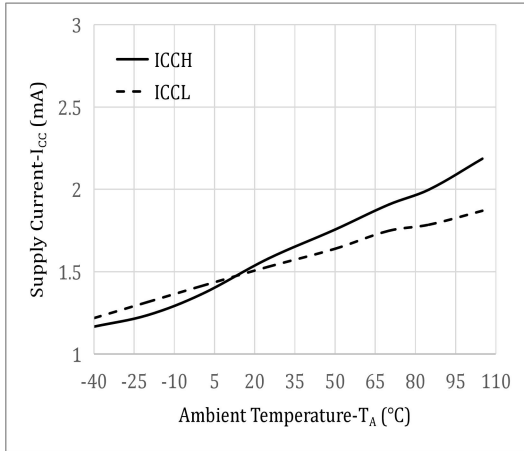


Fig.8 Supply Current vs. Supply Voltage

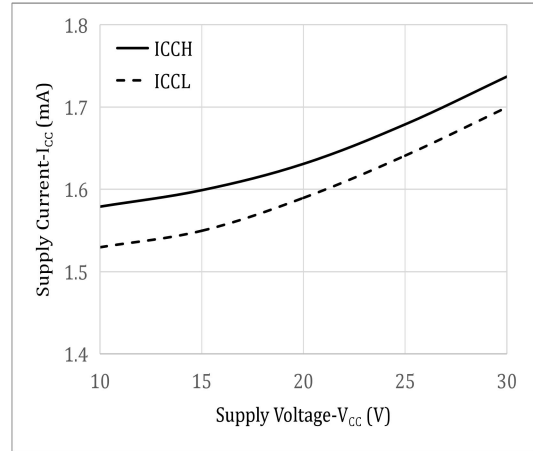


Fig.9 Threshold Input Current Low to High vs. Ambient Temperature

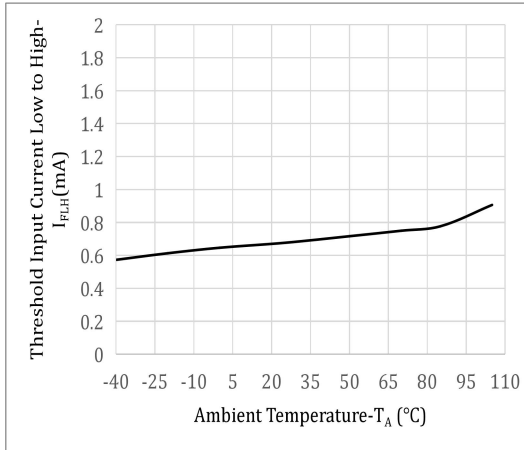


Fig.10 Propagation Delay vs. Supply Voltage

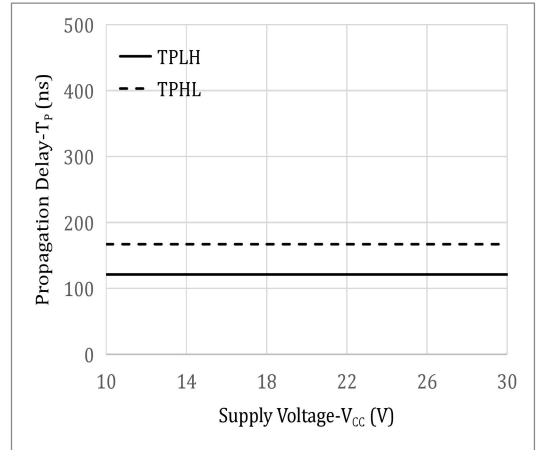


Fig.11 Propagation Delay vs. Input Forward Current

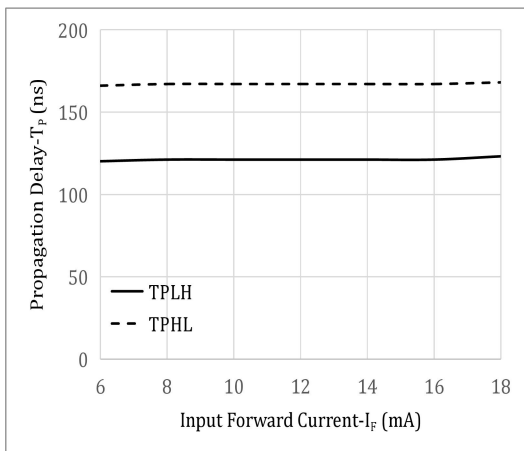


Fig.12 Propagation Delay vs. Ambient Temperature

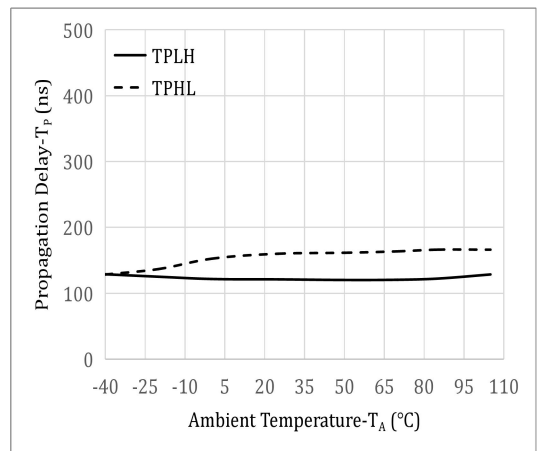




Fig.13 Propagation Delay vs. Load Resistance

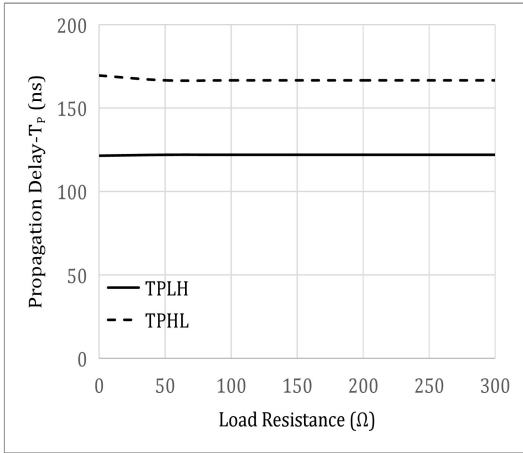


Fig.14 Propagation Delay vs. Load Capacitance

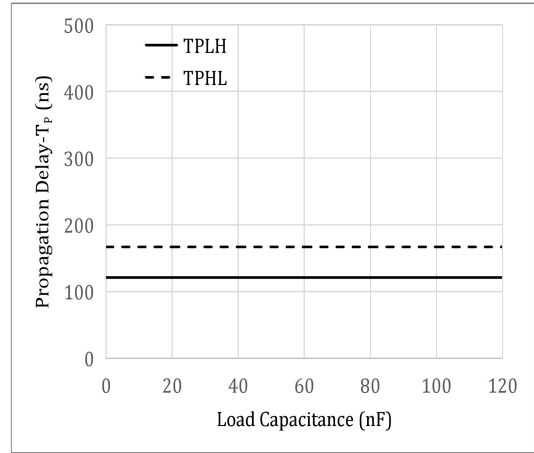


Fig.15 Output Voltage vs. Input Forward Current

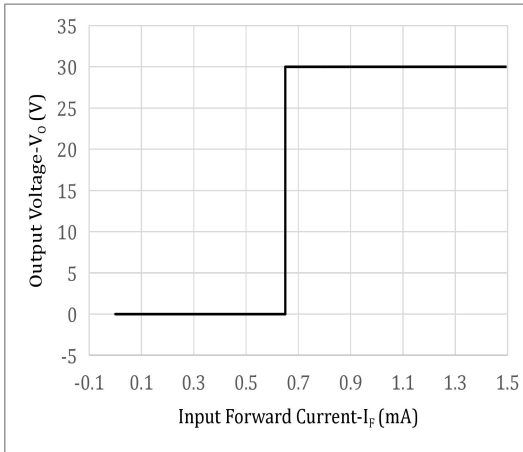
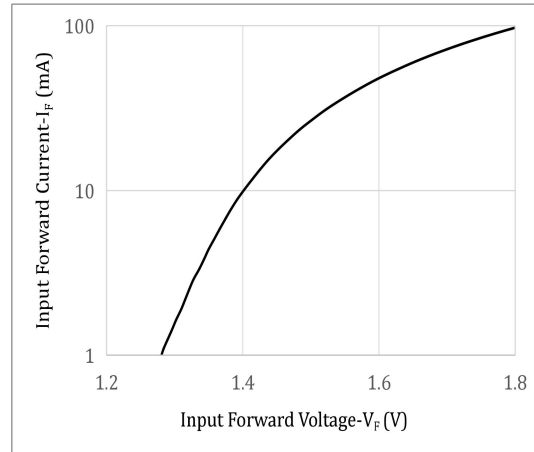


Fig.16 Input Forward Current vs Input Forward Voltage



**测试电路 Test Circuits**

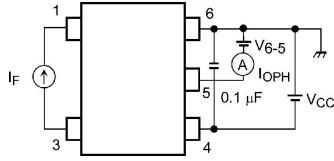


Fig17.  $I_{OH}$  Test Circuit

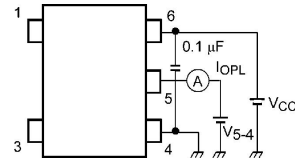
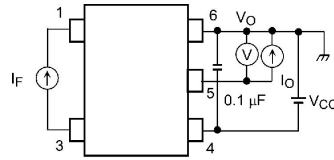


Fig18.  $I_{OL}$  Test Circuit



\* $V_{OH} = V_{CC} - V_O$   
Fig19.  $V_{OH}$  Test Circuit

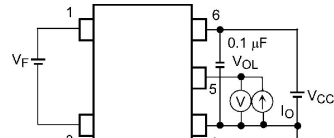


Fig20.  $V_{OL}$  Test Circuit

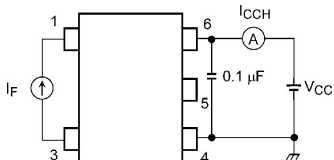


Fig21.  $I_{CCH}$  Test Circuit

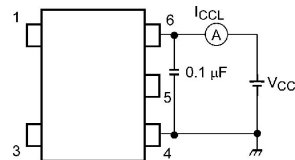
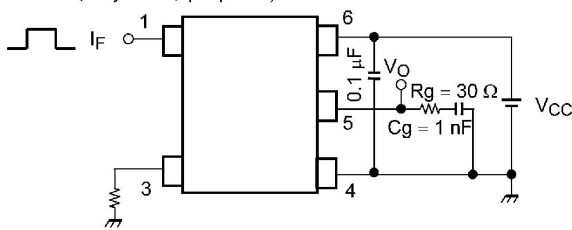


Fig22.  $I_{CCL}$  Test Circuit

$I_F = 10 \text{ mA (P.G.)}$   
( $f = 250 \text{ kHz}$ ,  $\text{duty} = 50\%$ ,  $t_r = t_f = 5 \text{ ns}$ )



P.G. : Pulse generator

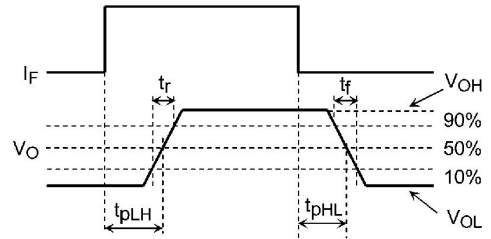
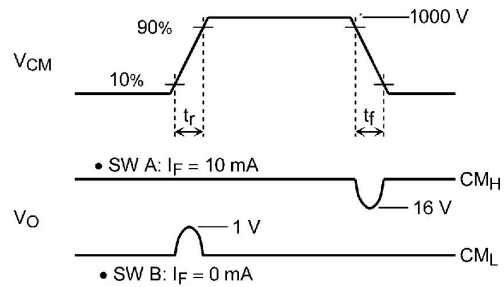
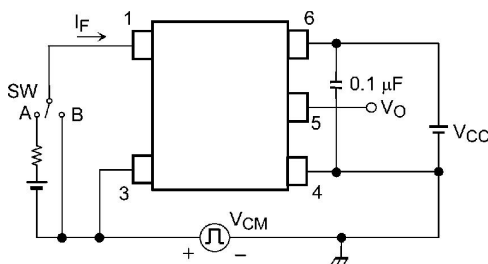


Fig23. Switching Time Test Circuit and Waveform



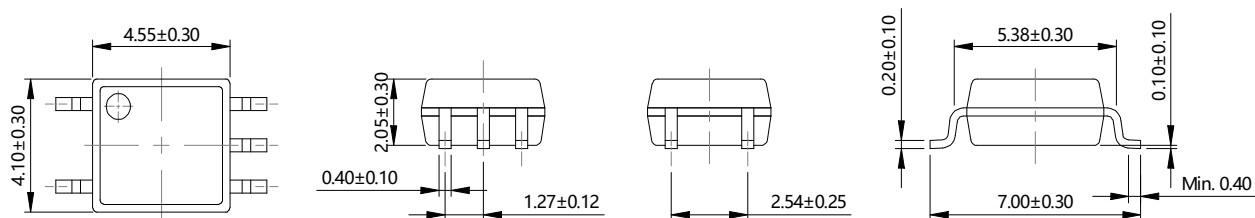
$$C_{ML} = \frac{800 \text{ V}}{t_r (\mu\text{s})}$$

$$C_{MH} = -\frac{800 \text{ V}}{t_f (\mu\text{s})}$$

Fig24. Common Mode Transient Immunity Test Circuit and Waveform

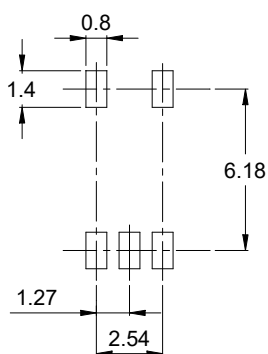
## 外形尺寸 Outline Dimensions

SOP5



单位 Unit: mm

## 建议焊盘布局 Recommended Pad Layout

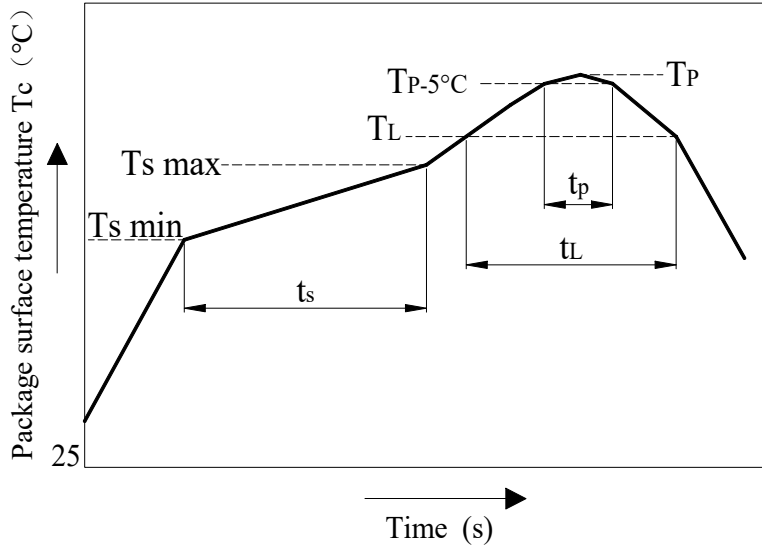


单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

**回流焊温度曲线图 Solder Reflow Profile**

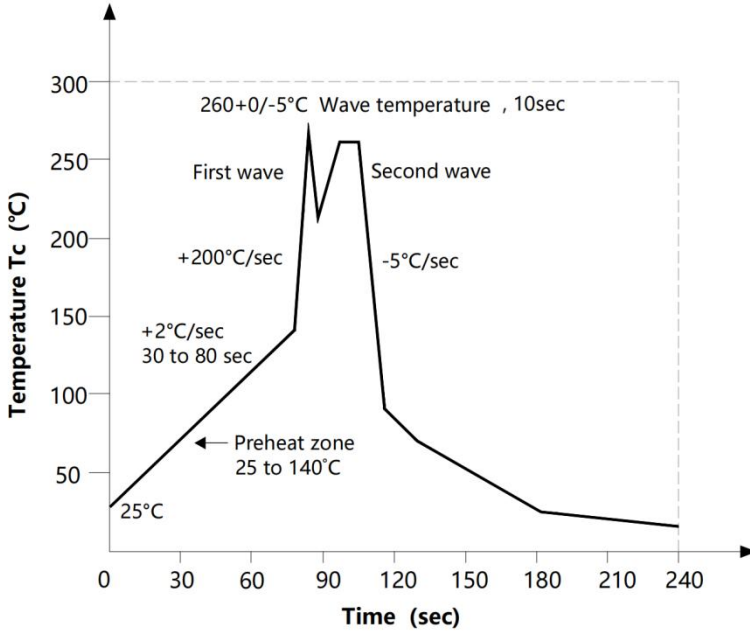


项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	$T_s$	150	200	°C
预热时间 Preheat Time	$t_s$	60	120	s
升温速率 Ramp-Up Rate ( $T_L$ to $T_P$ )	-	-	3	°C/s
液相线温度 Liquidus Temperature	$T_L$	217		°C
时间高于 $T_L$ Time Above $T_L$	$t_L$	60	150	s
峰值温度 Peak Temperature	$T_P$	-	260	°C
$T_C$ 在 $(T_P-5)$ 和 $T_P$ 之间的时间 Time During Which $T_C$ Is Between $(T_P-5)$ and $T_P$	$t_p$	-	30	s
降温速率 Ramp-down Rate ( $T_P$ to $T_L$ )	-	-	6	°C/s

注意：建议在所示的温度和时间条件下进行回流焊，最多不能超过三次。

Note: Reflow soldering is recommended at the temperatures and times shown, no more than three times.

**波峰焊温度曲线图 Wave Soldering Profile**



**手工烙铁焊接 Soldering with hand soldering iron**

- A. 手工烙铁焊仅用于产品返修或样品测试;  
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求: 温度 360°C ± 5°C, 时间 ≤ 3s。  
Manual soldering method Temperature: 360°C ± 5°C, within 3s.

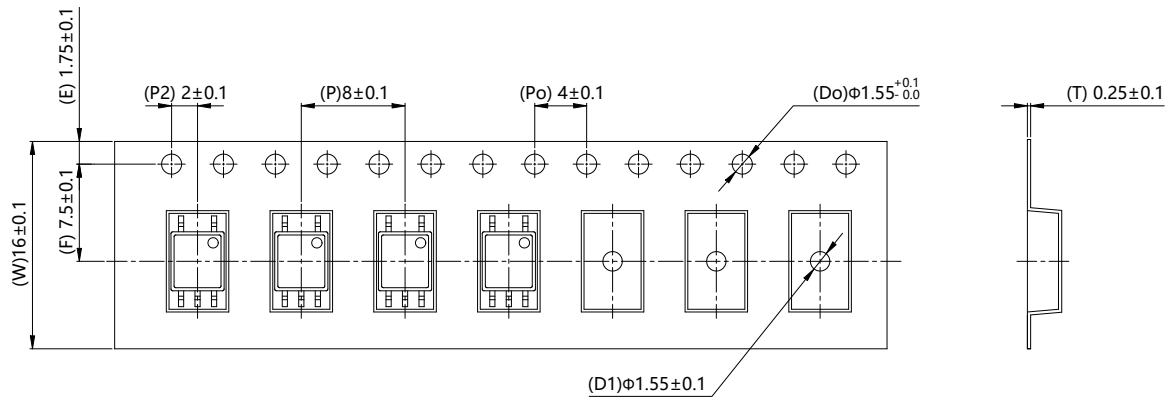
**包装 Packing**

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SOP5	卷盘 (φ330mm 蓝盘)	3000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1 mm	353*340*60 mm	650*375*365mm	首端空 50 个空格, 末端空 100 个空格
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SOP5	Reel (φ330mm Blue)	3000 pcs/reel	2 reels/box	10 boxes/ctn	450*390*0.1 mm	353*340*60 mm	650*375*365mm	Leave 50 Spaces at the beginning and 100 Spaces at the end

■ 编带包装 Tape & Reel

- 1) 每卷数量: 3000 只。  
Qty/reel: 3000pcs.
- 2) 每箱数量: 60000 只。  
Qty/ctn: 60000pcs.
- 3) 内包装: 每盒 2 盘。  
Inner packing: 2 reels/box.
- 4) 示意图 Schematic:



单位 Unit: mm

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